

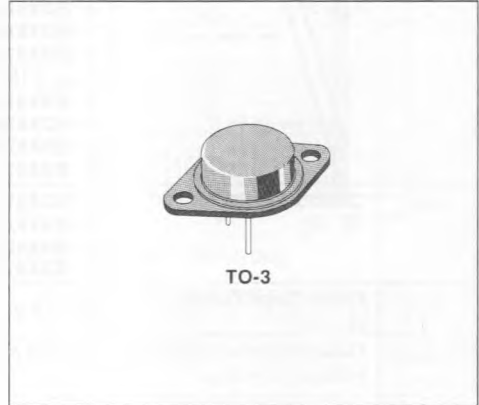


POWER DARLINGTONS

DESCRIPTION

The BDX87, BDX87A, BDX87B and BDX87C are silicon epitaxial-base NPN power transistors in monolithic Darlington configuration and are mounted in Jedec TO-3 metal case. They are intended for use in power linear and switching applications.

The complementary PNP types are the BDX88, BDX88A, BDX88B and BDX88C respectively.



INTERNAL SCHEMATIC DIAGRAMS



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	NPN PNP*	Value				Unit
			BDX87 BDX88	BDX87A BDX88A	BDX87B BDX88B	BDX87C BDX88C	
V _{CB0}	Collector-base Voltage (I _E = 0)		45	60	80	100	V
V _{CE0}	Collector-emitter Voltage (I _B = 0)		45	60	80	100	V
V _{EB0}	Emitter-base Voltage (I _C = 0)		5				V
I _C	Collector Current		12				A
I _{CM}	Collector Peak Current (repetitive)		18				A
I _B	Base Current		0.2				A
P _{tot}	Total Power Dissipation at T _{case} ≤ 25 °C		120				W
T _{stg}	Storage Temperature		- 65 to 200				°C
T _j	Junction Temperature		200				°C

* For PNP types voltage and current values are negative.

THERMAL DATA

$R_{th(j-case)}$	Thermal Resistance Junction-case	Max	1.45	°C/W
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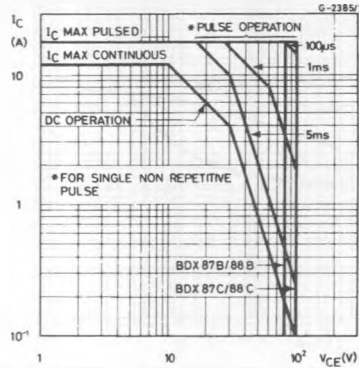
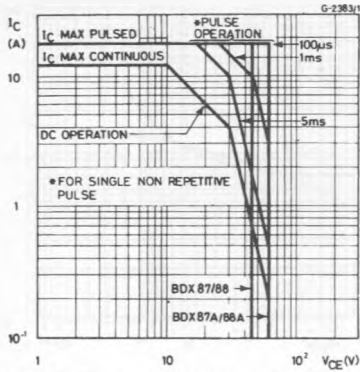
ELECTRICAL CHARACTERISTICS ($T_{case} = 25\text{ °C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
I_{CBO}	Collector Cutoff Current ($I_E = 0$)	for BDX87/8 $V_{CB} = 45\text{ V}$			500	μA	
		for BDX87A/8A $V_{CB} = 60\text{ V}$			500	μA	
		for BDX87B/8B $V_{CB} = 80\text{ V}$			500	μA	
		for BDX87C/8C $V_{CB} = 100\text{ V}$			500	μA	
		$T_{case} = 150\text{ °C}$					
		for BDX87/8 $V_{CB} = 45\text{ V}$			5	mA	
		for BDX87A/8A $V_{CB} = 60\text{ V}$			5	mA	
		for BDX87B/8B $V_{CB} = 80\text{ V}$			5	mA	
		for BDX87C/8C $V_{CB} = 100\text{ V}$			5	mA	
I_{CEO}	Collector Cutoff Current ($I_B = 0$)	for BDX87/8 $V_{CE} = 22\text{ V}$			1	mA	
		for BDX87A/8A $V_{CE} = 30\text{ V}$			1	mA	
		for BDX87B/8B $V_{CE} = 40\text{ V}$			1	mA	
		for BDX87C/8C $V_{CE} = 50\text{ V}$			1	mA	
I_{EBO}	Emitter Cutoff Current ($I_C = 0$)	$V_{EB} = 5\text{ V}$			1	mA	
$V_{CEO(sus)}^*$	Collector-emitter Sustaining Voltage ($I_B = 0$)	$I_C = 100\text{ mA}$	for BDX87/88	45		V	
			for BDX87A/88A	60		V	
			for BDX87B/88B	80		V	
			for BDX87C/88C	100		V	
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 6\text{ A}$	$I_B = 24\text{ mA}$		2	V	
		$I_C = 12\text{ A}$	$I_B = 120\text{ mA}$		3	V	
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	$I_C = 12\text{ A}$	$I_B = 120\text{ mA}$		4	V	
V_{BE}^*	Base-emitter Voltage	$I_C = 6\text{ A}$	$V_{CE} = 3\text{ V}$		2.8	V	
h_{FE}^*	DC Current Gain	$I_C = 5\text{ A}$	$V_{CE} = 3\text{ V}$	1000			
		$I_C = 6\text{ A}$	$V_{CE} = 3\text{ V}$	750		18000	
		$I_C = 12\text{ A}$	$V_{CE} = 3\text{ V}$	100			
V_F	Parallel-diode Forward Voltage	$I_F = 3\text{ A}$			2.5	V	
		$I_F = 8\text{ A}$			1.8	V	
h_{fe}	Small Signal Current Gain	$I_C = 5\text{ A}$	$V_{CE} = 3\text{ V}$		25		
		$f = 1\text{ MHz}$					

* Pulsed : pulse duration = 300 μs , duty cycle = 1.5%.
For PNP type voltage and current values are negative.

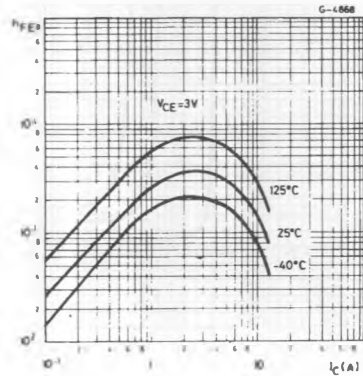
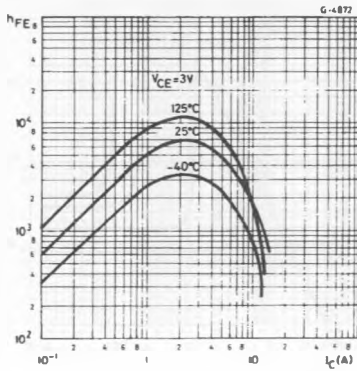
Safe Operating Areas (for BDX87, BDX87A, BDX88, BDX88A).

Safe Operating Areas (for BDX87A, BDX87C, BDX88B, BDX88C).



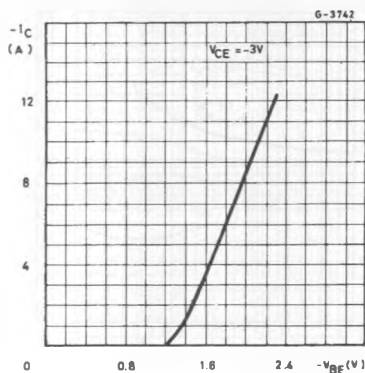
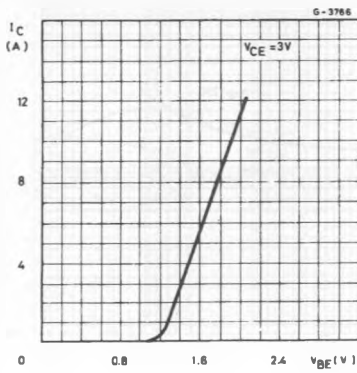
DC Current Gain (NPN types).

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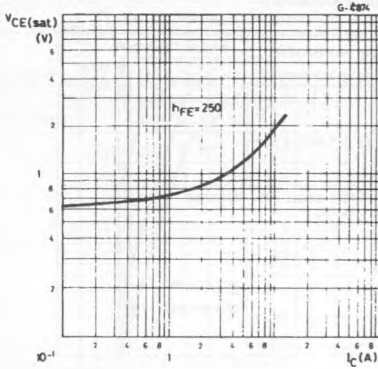


DC Transconductance (NPN types).

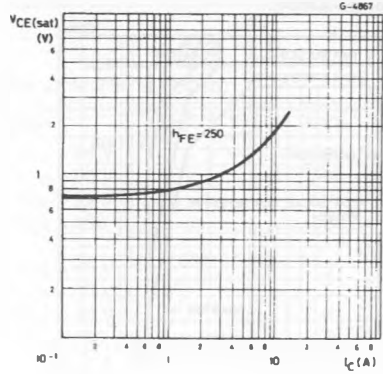
DC Transconductance (PNP types).



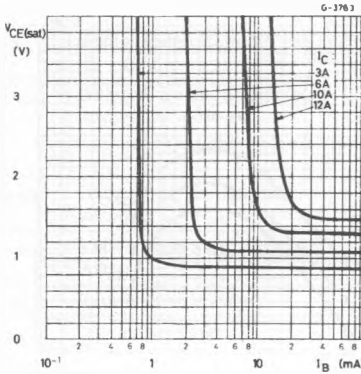
Collector-emitter Saturation Voltage (NPN types).



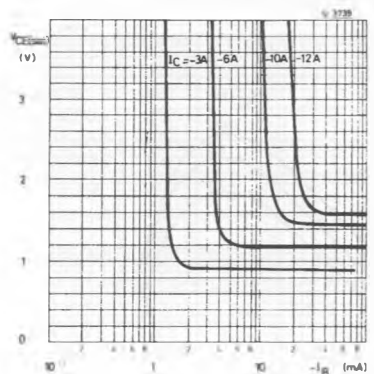
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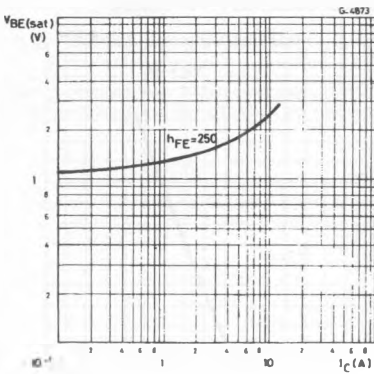
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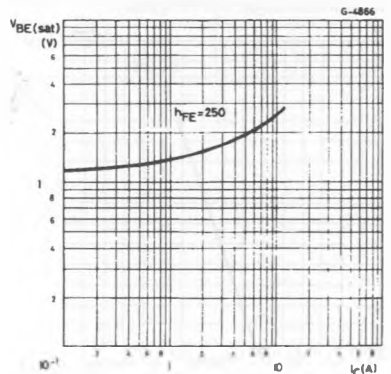
Collector-emitter Saturation Voltage (PNP types).



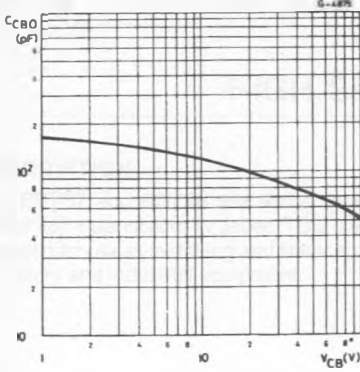
Base-emitter Saturation Voltage (NPN types).



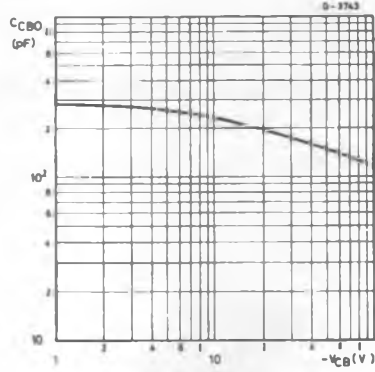
Base-emitter Saturation Voltage (PNP types).



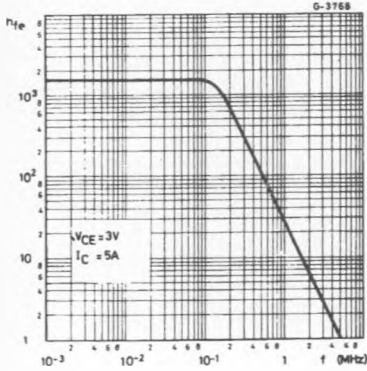
Collector-base Capacitance (NPN types).



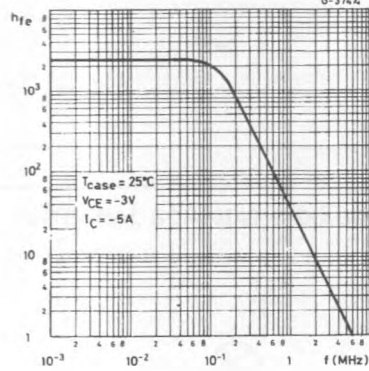
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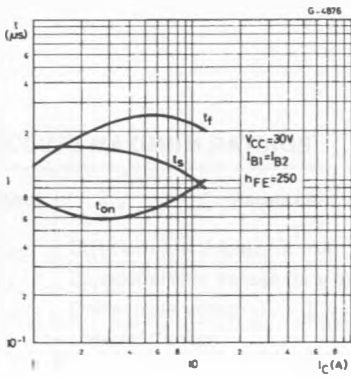
Small Signal Current Gain (NPN types).



Small Signal Current Gain (PNP types).



Saturated Switching Characteristics (NPN types).



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